

## N-Channel Super Junction Power MOSFET $\, III \,$

### **General Description**

The series of devices use advanced trench gate super junction technology and design to provide excellent R<sub>DS(ON)</sub> with low gate charge. This super junction MOSFET fits the industry's AC-DC SMPS requirements for PFC, AC/DC power conversion, and industrial power applications.

#### Features

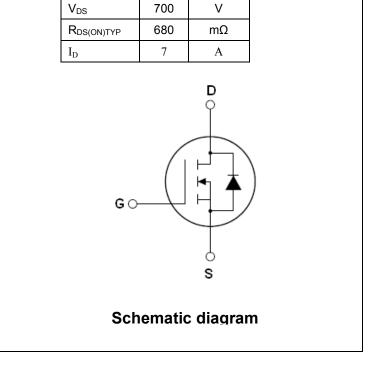
- •New technology for high voltage device
- •Low on-resistance and low conduction losses
- Small package
- ●Ultra Low Gate Charge cause lower driving requirements
- ●100% Avalanche Tested
- ●ROHS compliant

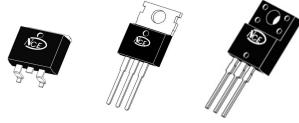
#### Application

- Power factor correction (PFC)
- Switched mode power supplies(SMPS)
- Uninterruptible Power Supply (UPS)

Package Marking And Ordering Information						
Device	Device Package	Marking				
NCE70T680D	TO-263	NCE70T680D				
NCE70T680	TO-220	NCE70T680				
NCE70T680F	TO-220F	NCE70T680F				

#### Table 1. Absolute Maximum Ratings (T<sub>c</sub>=25℃)





TO-263

TO-220

TO-220F

Parameter	Symbol	NCE70T680D NCE70T680	NCE70T680F	Unit
Drain-Source Voltage (V <sub>GS=0V</sub> )	VDS	70	00	V
Gate-Source Voltage (VDS=0V) AC (f>1 Hz)	Vgs	±	±30	
Continuous Drain Current at Tc=25°C	I <sub>D (DC)</sub>	7	7*	А
Continuous Drain Current at Tc=100°C	D (DC)	4.5	4.5*	А
Pulsed drain current (Note 1)	DM (pluse)	28	28*	А
Maximum Power Dissipation(Tc=25°C)	P <sub>D</sub>	60	31.4	W
Derate above 25°C		0.48	0.25	W/°C
Single pulse avalanche energy (Note 2)	Eas	101		mJ
Avalanche current <sup>(Note 1)</sup>	I <sub>AR</sub>	1.5		А
Repetitive Avalanche energy , $t_{\text{AR}}$ limited by $T_{\text{jmax}}$ (Note 1)	E <sub>AR</sub>	0.:	28	mJ



## NCE70T680D,NCE70T680,NCE70T680F

Parameter	Symbol	NCE70T680D NCE70T680	NCE70T680F	Unit
Drain Source voltage slope, $V_{DS} \leq 480 V$ ,	dv/dt	50		V/ns
Reverse diode dv/dt, $V_{DS} \leqslant 480 V, I_{SD} < I_D$	dv/dt	1	5	V/ns
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55	+150	°C

\* limited by maximum junction temperature

#### Table 2. Thermal Characteristic

Parameter	Symbol	NCE70T680D NCE70T680	NCE70T680F	Unit
Thermal Resistance, Junction-to-Case (Maximum)	R <sub>thJC</sub>	2.08	3.98	°C /W
Thermal Resistance, Junction-to-Ambient (Maximum)	R <sub>thJA</sub>	62	80	°C /W

### Table 3. Electrical Characteristics (TA=25 $^{\circ}$ Cunless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
On/off states						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	700			V
Zero Gate Voltage Drain Current(Tc=25°C)	I <sub>DSS</sub>	V <sub>DS</sub> =700V,V <sub>GS</sub> =0V			1	μA
Zero Gate Voltage Drain Current(Tc=125℃)	I <sub>DSS</sub>	V <sub>DS</sub> =700V,V <sub>GS</sub> =0V			100	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V			±100	nA
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250µA	3		4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =3.5A		680	760	mΩ
Dynamic Characteristics	·					
Input Capacitance	Clss			435		pF
Output Capacitance	Coss	V <sub>DS</sub> =50V,V <sub>GS</sub> =0V,		28		pF
Reverse Transfer Capacitance	Crss	F=1.0MHz		3.3		pF
Total Gate Charge	Qg	V = 400V/L = 7A		11		nC
Gate-Source Charge	Q <sub>gs</sub>	- V <sub>DS</sub> =480V,I <sub>D</sub> =7A, V <sub>GS</sub> =10V		3.5		nC
Gate-Drain Charge	Q <sub>gd</sub>	VGS=10V		5		nC
Switching times	·					
Turn-on Delay Time	t <sub>d(on)</sub>			8.5		nS
Turn-on Rise Time	tr	V <sub>DD</sub> =420V,I <sub>D</sub> =3.5A,		7		nS
Turn-Off Delay Time	t <sub>d(off)</sub>	R <sub>G</sub> =4.7Ω,V <sub>GS</sub> =10V		59	77	nS
Turn-Off Fall Time	t <sub>f</sub>			9.5	16	nS
Source- Drain Diode Characteristics	·					
Source-drain current(Body Diode)	I <sub>SD</sub>	T -25%0			7	Α
Pulsed Source-drain current(Body Diode)	I <sub>SDM</sub>	T <sub>C</sub> =25°C			28	Α
Forward On Voltage	V <sub>SD</sub>	Tj=25°C,I <sub>SD</sub> =7A,V <sub>GS</sub> =0V		0.9	1.2	V
Reverse Recovery Time	t <sub>rr</sub>			210		nS
Reverse Recovery Charge	Q <sub>rr</sub>			0.85		uC
Peak Reverse Recovery Current	I <sub>rrm</sub>			8		Α

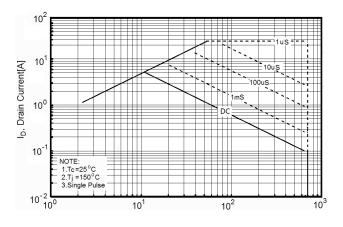
Notes 1.Repetitive Rating: Pulse width limited by maximum junction temperature

2. Tj=25°C,VDD=50V,VG=10V, R\_G=25\Omega



### TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS (curves)

#### Figure1. Safe operating area



#### Figure3. Source-Drain Diode Forward Voltage

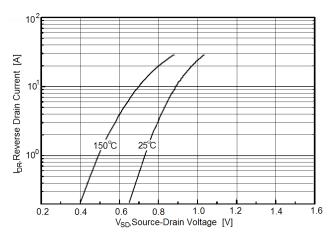
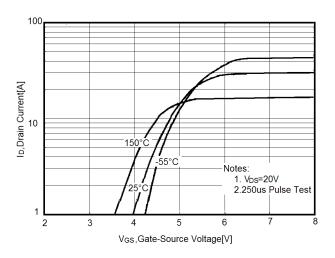


Figure 5. Transfer characteristics



#### Figure 2. Safe operating area for TO-220F

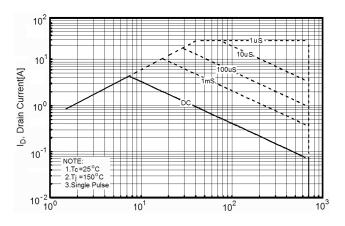


Figure4. Output characteristics

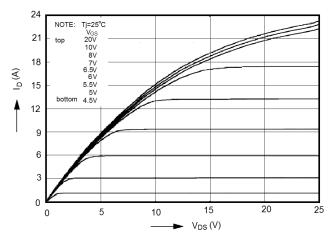
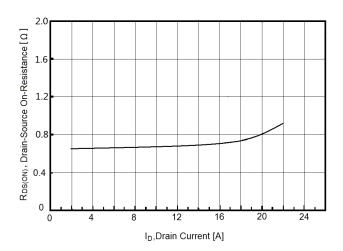


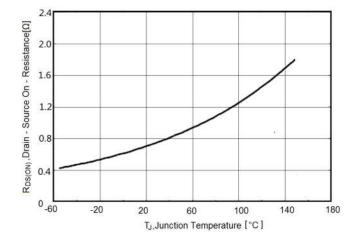
Figure6. Static drain-source on resistance

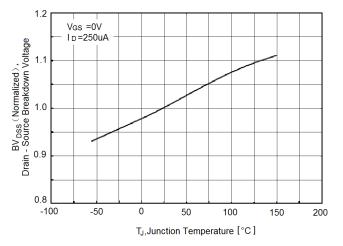




#### Figure7. R<sub>DS(ON)</sub> vs Junction Temperature

#### Figure8. BV<sub>DSS</sub> vs Junction Temperature





#### Figure9. Maximum $I_D$ vs Junction Temperature

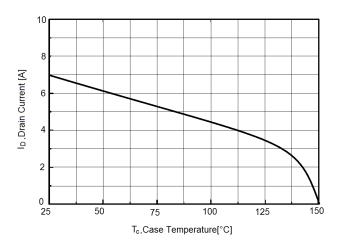


Figure11. Gate charge waveforms



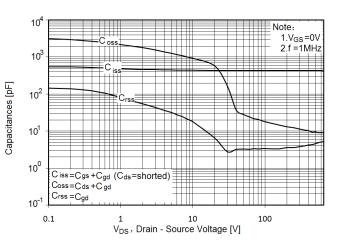
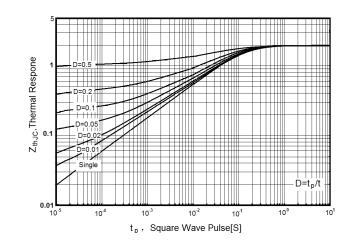
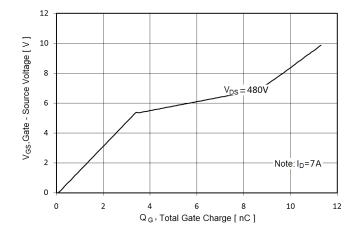


Figure12. Transient Thermal Impedance

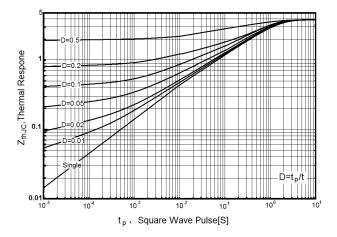




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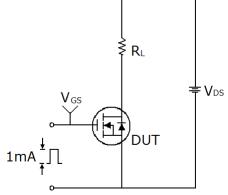
### Figure13. Transient Thermal Impedance for TO-220F

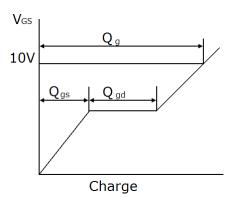




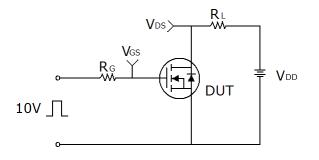
## Test circuit

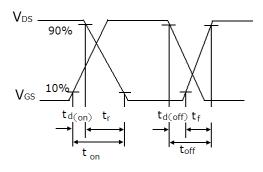
1) Gate charge test circuit & Waveform



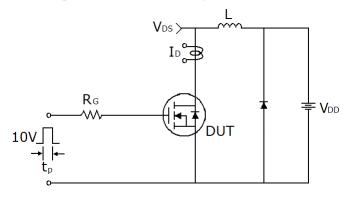


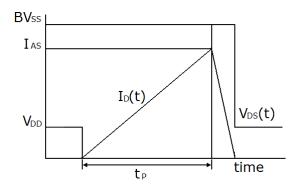
2) Switch Time Test Circuit:





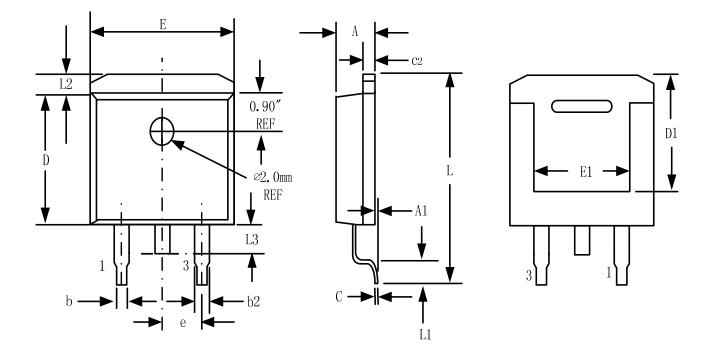
3) Unclamped Inductive Switching Test Circuit & Waveforms







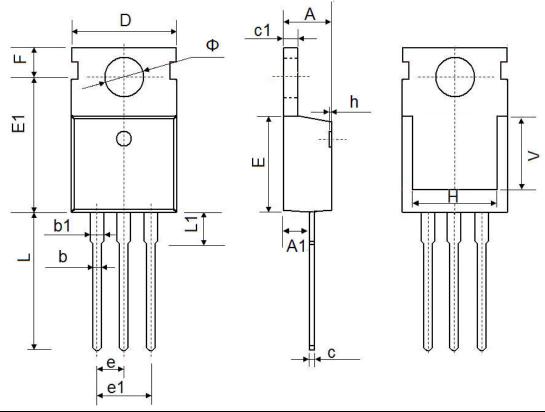
## **TO-263-3L Package Information**



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	4.32	4.57	0.170	0.180	
A1	-	0.25		0.010	
b	0.71	0.94	0.028	0.037	
b2	1.15	1.40	0.045	0.055	
с	0.46	0.61	0.018	0.024	
c2	1.22	1.40	0.048	0.055	
D	8.89	9.40	0.350	0.370	
D1	8.01	8.23	0.315	0.324	
E	10.04	10.28	0.395	0.405	
E1	7.88	8.08	0.310	0.318	
e	2.54	2.54 BSC		BSC	
L	14.73	15.75	0.580	0.620	
L1	2.29	2.79	0.090	0.110	
L2	1.15	1.39	0.045	0.055	
L3	1.27	1.77	0.050	0.070	



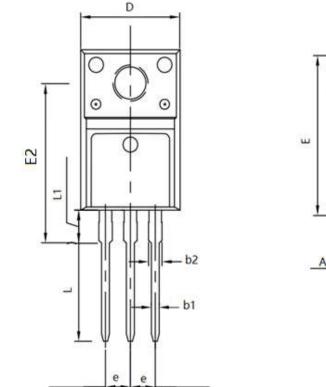
# **TO-220-3L-C Package Information**

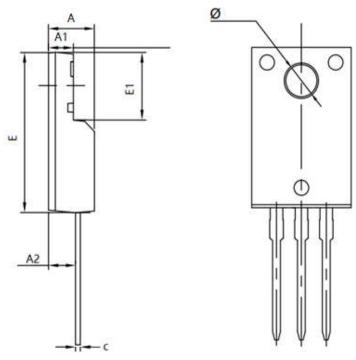


Symphol	Dimensions	Dimensions In Millimeters		s In Inches
Symbol	Min.	Max.	Min.	Max.
А	4.400	4.600	0.173	0.181
A1	2.250	2.550	0.089	0.100
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
С	0.330	0.650	0.013	0.026
c1	1.200	1.400	0.047	0.055
D	9.910	10.250	0.390	0.404
E	8.9500	9.750	0.352	0.384
E1	12.650	12.950	0.498	0.510
е	2.540 TYP.		0.100 TYP.	
e1	4.980	5.180	0.196	0.204
F	2.650	2.950	0.104	0.116
Н	7.900	8.100	0.311	0.319
h	0.000	0.300	0.000	0.012
L	12.900	13.400	0.508	0.528
L1	2.850	3.250	0.112	0.128
V	7.500 REF.		0.295 REF.	
Ф	3.400	3.800	0.134	0.150



# **TO-220F Package Information**





Symbol	Dimensions	In Millimeters	<b>Dimensions In Inches</b>		
	Min.	Max.	Min.	Max.	
А	4.500	4.900	0.177	0.193	
A1	2.340	2.740	0.092	0.108	
A2	2.560	2.960	0.101	0.117	
b1	0.700	0.900	0.028	0.035	
b2	1.180	1.580	0.046	0.062	
С	0.400	0.600	0.016	0.024	
D	9.960	10.360	0.392	0.408	
E	15.670	15.970	0.617	0.629	
E1	6.500	6.900	0.256	0.272	
E2	15.500	16.100	0.610	0.634	
e	2.54	0 TYP	0.100	) TYP	
Φ	3.080	3.280	0.121	0.129	
L	12.640	13.240	0.498	0.521	
L1	3.030	3.430	0.119	0.135	



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